TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HCT273AP,TC74HCT273AF

Octal D-Type Flip Flop with Clear

The TC74HCT273A is a high speed CMOS OCTAL D-TYPE FLIP FLOP fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Their inputs are compatible with TTL, NMOS, and CMOS output voltage levels.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the $\overline{\text{CLR}}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 90 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- Compatible with TTL outputs: $V_{IH} = 2.0 \text{ V (min)}$

 $V_{IL} = 0.8 \text{ V (max)}$

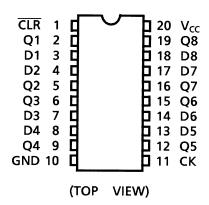
- Wide interfacing ability: LSTTL, NMOS, CMOS
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74LS273

DIP20-P-300-2.54A TC74HCT273AF SOP20-P-300-1.27A

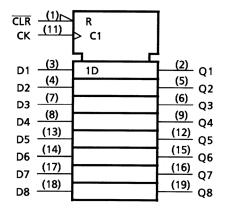
Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.)

Pin Assignment



IEC Logic Symbol

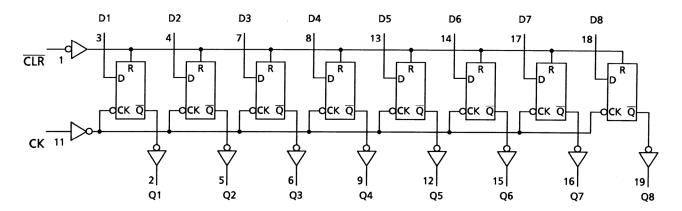


Truth Table

	Inputs		Output	Function
CLR	D	CK	Q	Tunction
L	Х	Х	L	Clear
Н	L		L	_
Н	Н		Н	_
Н	Х		Qn	No Change

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	٧
Input diode current	l _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	−65 ~ 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of $Ta = -40\sim65$ °C. From Ta = 65 to 85 °C a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5~5.5	V
Input voltage	VIN	0~V _{CC}	V
Output voltage	Vout	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	t _r , t _f	0~500	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

			Test Condition		Ta = 25°C			Ta = -40~85°C		
Characteristics	Symbol			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
High-level input voltage	V _{IH}		_	4.5~ 5.5	2.0	_	_	2.0		٧
Low-level input voltage	V _{IL}	_		4.5~ 5.5	_	_	0.8	_	0.8	V
High-level output	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	4.5	4.4	4.5	_	4.4		V
voltage			I _{OH} = -4 mA	4.5	4.18	4.31	_	4.13		
Low-level output	V _{OL} =	V _{IN}	I _{OL} = 20 μA	4.5	-	0.0	0.1	_	0.1	.,
voltage		= V _{IH} or V _{IL}	I _{OL} = 4 mA	4.5		0.17	0.26	_	0.33	V
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5		_	±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	-	_	4.0	_	40.0	μΑ
	Ic	Per input: V _{IN} = 0.5 V or 2.4 V Other input: V _{CC} or GND		5.5		_	2.0	_	2.9	mA



Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Test Condition			Ta = -40 ~85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit		
Minimum pulse width	t _{W (L)}		4.5	_	15	19	no	
(CK)	t _{W (H)}	_	5.5	_	14	17	ns	
Minimum pulse width	4		4.5	_	15	19		
(CLR)	t _{W (L)}	_	5.5	_	14	17	ns	
Minimum set-up time	ts	_	4.5	_	10	13	ns	
williminam set-up time			5.5	_	10	13		
Minimum hold time	t _h		4.5	_	5	6	ns	
William Hold time			5.5		10	13		
Minimum removal time	•		4.5	_	10	13	no	
(CLR)	t _{rem}	_	5.5	_	9	12	ns	
Clock fraguency	f		4.5	_	30	24	MUZ	
Clock frequency		_	5.5	_	35	28	MHz	

AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: t_r = t_f = 6 ns)

Characteristics	Symbol Test Condition		Min	Тур.	Max	Unit
Output transition time	t _{TLH} t _{THL}	_	_	4	8	ns
Propagation delay time (CK-Q)	t _{pLH}	_	_	15	25	ns
Propagation delay time (CLR -Q)	t _{pHL}	_	_	18	28	ns
Maximum clock frequency	f _{max}	_	40	90	_	MHz



AC Characteristics ($C_L = 50$ pF, input: $t_r = t_f = 6$ ns)

		Test Condition		-	Га = 25°C		Ta = -4		
Characteristics	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Output transition time	t _{TLH}		4.5	_	9	15	_	19	ns
Output transition time	t _{THL}	_	5.5	_	8	14	_	18	115
Propagation delay time	t _{pLH}	_	4.5	_	19	30	_	38	ns
(CK-Q)	t_{pHL}		5.5	_	17	27	_	34	110
Propagation delay time	t _{pLH}	_	4.5	_	22	32	_	40	ns
(CLR -Q)	t_{pHL}		5.5	_	18	29	_	36	110
Maximum clock	£		4.5	30	71		24		MHz
frequency	f _{max}	_	5.5	35	81	_	28	_	IVITZ
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)	_		_	29	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

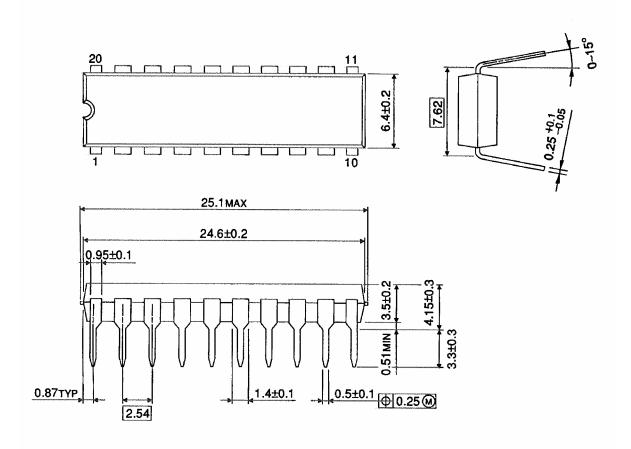
$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per flip flop)

And the total C_{PD} when n pcs. of flip flop operate can be gained by the following equation:

$$C_{PD}$$
 (total) = 18 + 11 · n

Package Dimensions

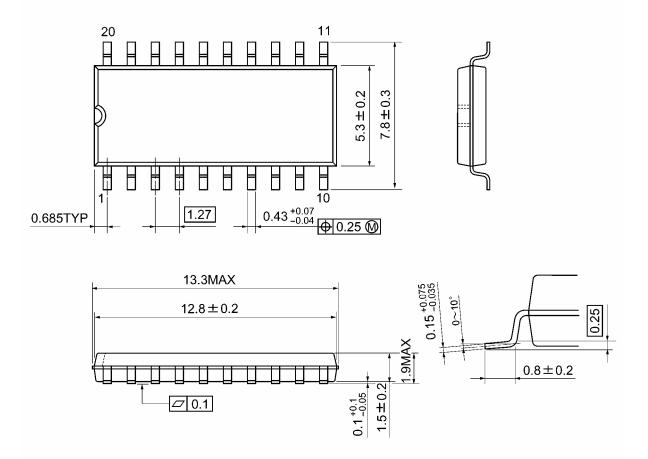
DIP20-P-300-2.54A Unit: mm



Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

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20070701-EN GENERAL

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